

RN2201~RN2206

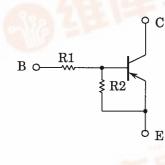
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2201,RN2202,RN2203 RN2204, RN2205, RN2206

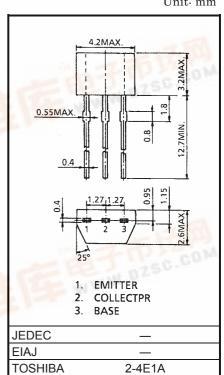
Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1201~RN1206 •

Equivalent Circuit and Bias Resistor Values



| Type No. | R1 (kΩ) | R2 (kΩ) | |
|----------|---------|---------|--|
| RN2201 | 4.7 | 4.7 | |
| RN2202 | 10 | 10 | |
| RN2203 | 22 | 22 | |
| RN2204 | 47 | 47 | |
| RN2205 | 2.2 | 47 | |
| RN2206 | 4.7 | 47 | |



Weight: 0.13g

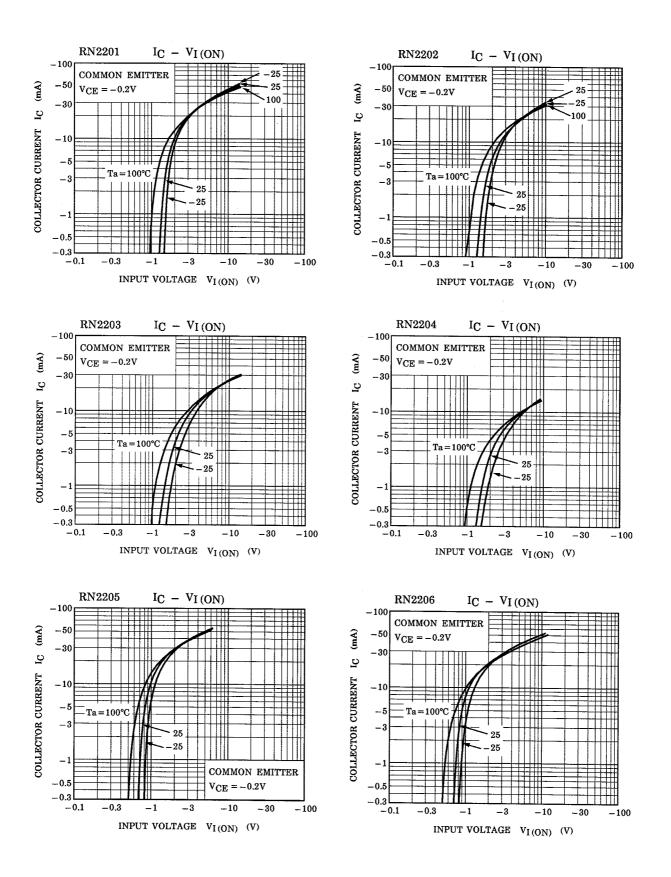
Maximum Ratings (Ta = 25°C)

| Characterist | ic | Symbol | Rating | Unit | 一一二市场网 |
|-----------------------------|--------------|------------------|----------|------|------------------|
| Collector-base voltage | RN2201~2206 | V _{CBO} | -50 | V | BHT WWW.DZSC.COM |
| Collector-emitter voltage | RIN2201~2200 | V _{CEO} | -50 | V | WWW |
| Emitter-base voltage | RN2201~2204 | V _{EBO} | -10 | V | |
| | RN2205, 2206 | | -5 | V | |
| Collector current | RN2201~2206 | Ic | -100 | mA | |
| Collector power dissipation | | PC | 300 | mW | |
| Junction temperature | | Tj | 150 | °C | |
| Storage temperature range | | T _{stg} | -55~150 | °C | -17.00 |
| | | | M | 1 | WWW.0ZSC.CON |

Unit: mm

Electrical Characteristics (Ta = 25°C)

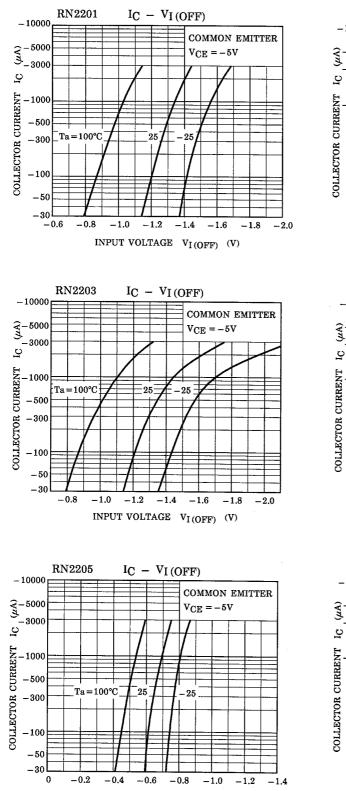
| Characteri | stic | Symbol | Test Circuit | Test Condition | Min | Тур. | Max | Unit |
|--------------------------------------|--------------|-----------------------|-----------------|---|--------|--------|--------|------------|
| Collector cut-off current | RN2201~2206 | I _{CBO} | — | $V_{CB} = -50V, I_E = 0$ | _ | — | -100 | n A |
| | RN2201~2200 | I _{CEO} | _ | $V_{CE} = -50V, I_B = 0$ | _ | _ | -500 | nA |
| Emitter cut-off current | RN2201 | IEBO | _ | V _{EB} = -10V, I _C = 0 | -0.82 | _ | -1.52 | mA |
| | RN2202 | | - | | -0.38 | _ | -0.71 | |
| | RN2203 | | — | | -0.17 | _ | -0.33 | |
| | RN2204 | | _ | | -0.082 | _ | -0.15 | |
| | RN2205 | | _ | V _{EB} = -5V, I _C = 0 | -0.078 | _ | -0.145 | |
| | RN2206 | | _ | | -0.074 | _ | -0.138 | |
| DC current gain | RN2201 | - h _{FE} | — | V _{CE} = -5V, I _C = -10mA | 30 | — | _ | _ |
| | RN2202 | | _ | | 50 | _ | _ | |
| | RN2203 | | _ | | 70 | _ | _ | |
| | RN2204 | | _ | | 80 | _ | _ | |
| | RN2205 | | _ | | 80 | _ | _ | |
| | RN2206 | | _ | - | 80 | _ | _ | |
| Collector-emitter saturation voltage | RN2201~2206 | V _{CE (sat)} | _ | I _C = −5mA, I _B = −0.25mA | _ | -0.1 | -0.3 | V |
| Input voltage (ON) | RN2201 | Vi (on) | _ | V _{CE} = -0.2V, I _C = -5mA | -1.1 | _ | -2.0 | V |
| | RN2202 | | _ | | -1.2 | _ | -2.4 | |
| | RN2203 | | _ | | -1.3 | _ | -3.0 | |
| | RN2204 | | _ | | -1.5 | _ | -5.0 | |
| | RN2205 | | _ | | -0.6 | _ | -1.1 | |
| | RN2206 | | _ | | -0.7 | _ | -1.3 | |
| Input voltage (OFF) | RN2201~2204 | VI (OFF) | _ | V _{CE} = -5V, I _C = -0.1mA | -1.0 | _ | -1.5 | V |
| | RN2205, 2206 | | _ | | -0.5 | — | -0.8 | |
| Translation frequency | RN2201~2206 | f _T | — | $V_{CE} = -10V, I_C = -5mA$ | _ | 200 | — | MHz |
| Collector output capacitance | RN2201~2206 | C _{ob} | - | V _{CB} = -10V, I _E = 0, f = 1MHz | - | 3 | 6 | pF |
| Input resistor | RN2201 | R1 | - | | 3.29 | 4.7 | 6.11 | kΩ |
| | RN2202 | | _ | | 7 | 10 | 13 | |
| | RN2203 | | _ | | 15.4 | 22 | 28.6 | |
| | RN2204 | | _ | | 32.9 | 47 | 61.1 | |
| | RN2205 | | _ | | 1.54 | 2.2 | 2.86 | |
| | RN2206 | | _ | | 3.29 | 4.7 | 6.11 | |
| | RN2201~2204 | 204 6 R1/R2 | _ | | 0.9 | 1.0 | 1.1 | _ |
| Resistor ratio | RN2205 | | _ | | 0.0421 | 0.0468 | 0.0515 | |
| | RN2206 | | _ | | 0.09 | 0.1 | 0.11 | |



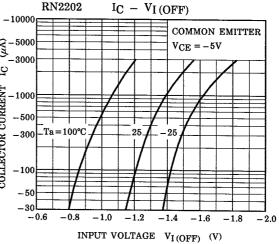
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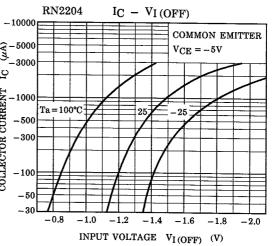
RN2201~RN2206

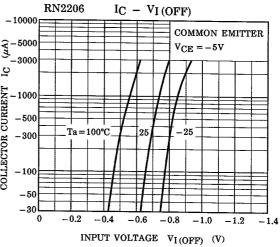
TOSHIBA



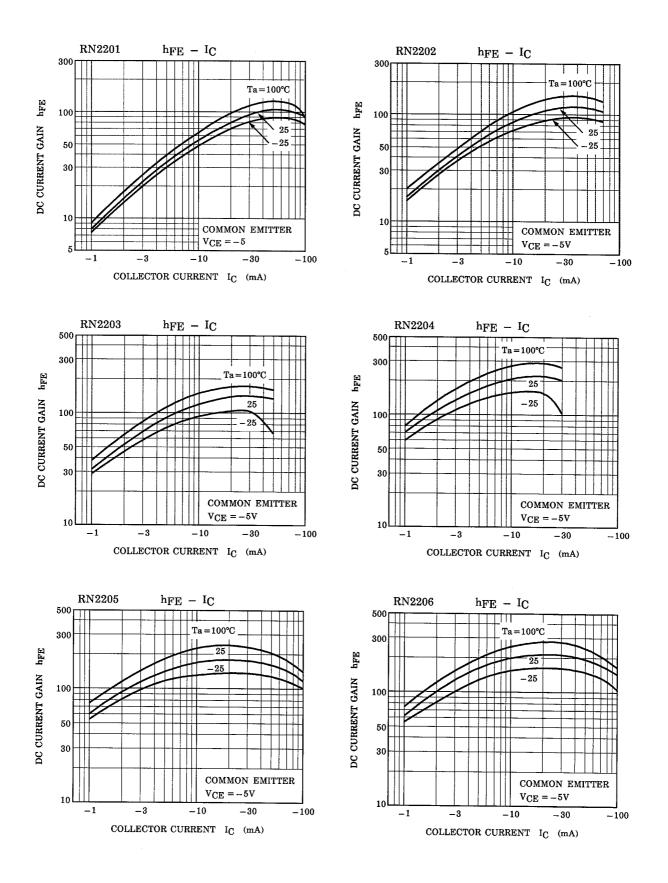
INPUT VOLTAGE VI(OFF) (V)







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